PCN Number: 20170			20170510000C			PC Da	CN ate:	Aug 24, 2017					
Title: Qualification of Amkor and TI Clark as an additional Assembly and Test Si select Devices						Sites and for							
Custon	ner C	ontact:	PCN M	anag	ger		De	ept:	Quality Ser	vice	es		
Proposed 1 st Ship Date:		Nov	v 24	24, 2017 Estimated Sample		Αv	Availability:		Provided upon Request				
Change	е Тур	e:											
\boxtimes	Asser	mbly Site			X	Assembly Process					Assembly	Materials	
	Desig	ın				Electrical Specification				Mechanical Specification			
\boxtimes	Test 9	Site				Packing/Shipping/Labeling				Test Proc	ess		
Wafer Bump Site				Wafer Bump Material				Wafer Bu	mp Process				
☐ Wafer Fab Site					Wafer Fab Materials				Wafer Fal	Process			
					Part number change								
	PCN Details												

Description of Change:

Revision C is to announce the addition of a new set of (Group 4) devices. The additional device group included below is in **bold highlight font**. The expected first shipment date for this new device will be 90 days from this notice.

Texas Instruments is pleased to announce the qualification of Amkor and TI Clark as and additional Assembly and Test site for the devices listed below. Construction differences are as follows:

Groups 1,2 and 3 Device:

What	PSi	TI Clark	Amkor	
Mold Compound	SID#202828	4208625	SID#101384766	
Lead finish	Matte Sn	NiPdAu	Matte Sn	
Bond Wire, Diameter	Au, 1.0 mils	Au, 1.0 mils	Au, 0.96 Mils	

Upon expiry of this PCN TI will combine lead free solutions in a single <u>standard part number</u>, for the <u>CSD58888Q5D</u> – can ship with both Matte Sn and NiPdAu/Ag.

Example:

- Customer order for 7500units of CSD58888Q5D with 2500 units SPQ (Standard Pack Quantity per Reel).
- TI can satisfy the above order in one of the following ways.
 - 3 Reels of NiPdAu finish.
 - II. 3 Reels of Matte Sn finish
 - III. 2 Reels of Matte Sn and 1 reel of NiPdAu finish.
 - IV. 2 Reels of NiPdAu and 1 reel of Matte Sn finish.

Group 4 Device:

What	Carsem	TI Clark
Mount Compound	SID#436781	4207768

Test coverage, insertions, conditions will remain consistent with current testing and verified with test MO.

Reason for Change:

Continuity of Supply

Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative):

None

Anticipated impact on Material Declaration

No Impact to the
Material Declaration

Material Declarations or Product Content reports are driven from production data and will be available following the production release. Upon production release the revised reports can be obtained from the TI Eco-Info website. There is no impact to the material meeting current regulatory compliance requirements with this PCN change.

Changes to product identification resulting from this PCN:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (21L)	Assembly City
PSI	PAC	PHL	Taguig City
Carsem	CRS	MYS	Jelapang
TI Clark	QAB	PHL	Angeles City
Amkor	AP3	PHL	Binan

Sample product shipping label (not actual product label)



MADE IN: Malaysia 2DC: 20: MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT: LBL: 5A (L)T0:1750



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483812 (P) (2P) REV: (V) 0033317 (20L) C\$0: SHE (21L) CCO: USA (22L) A\$0: MLA (23L) ACO: MYS

Topside Device marking (if included):

Assembly site code for PAC= E Assembly site code for CRS= W Assembly site code for QAB = I Assembly site code for AP3 = 3

Product Affected

Group 1 Device list: Current AT site = PSi & Clark, Additional AT site = Amkor

Group 2 Device list: Current AT site= PSi, Additional AT site = Amkor

CSD17575Q3	CSD18532NQ5B	CSD19502Q5B	SN1607042Q5B
CSD1757503T	CSD18532NQ5BT	CSD1950205BT	

Group 4 Device list: Current AT site= Carsem , Additional AT site = TI Clark

TPS65131RGER TPS65131RGET



Qualification Report

Phase 7 Power Block Qual in Amkor P3: CSD87333Q3D, CSD87334Q3D, CSD87335Q3D Approve Date 06-February-2017

Product Attributes

Attributes	Qual Device: CSD87333Q3D	Qual Device: CSD87334Q3D	Qual Device: CSD87335Q3D
Assembly Site	AMKOR P3 A/T PHIL	AMKOR P3 A/T PHIL	AMKOR P3 A/T PHIL
Package Family	DQZ	DQZ	DQZ
Flammability Rating	UL 94 V-0	UL 94 V-0	UL 94 V-0
Wafer Fab Supplier	CFAB	CFAB	CFAB
Wafer Fab Process	NEXFET-LV 30N10	NEXFET-LV 30N10	NEXFET-LV 30N10

- QBS: Qual By Similarity
- Qual Device CSD87333Q3D is qualified at LEVEL1-260C
- Qual Device CSD87335Q3D is qualified at LEVEL1-260C
- Qual Device CSD87334Q3D is qualified at LEVEL1-260C
- Device CSD87333Q3D contains multiple dies.
- Device CSD87334Q3D contains multiple dies.
- Device CSD87335Q3D contains multiple dies.

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: CSD87333Q3D	Qual Device: CSD87334Q3D	Qual Device: CSD87335Q3D
MQ	Manufacturability (Assembly)	(per mfg. Site specification)	3/1/0 - Pass	3/1/0 - Pass	3/1/0 - Pass
PC	Preconditioning	(per the appropriate pkg level)	-	3/462/0	3/462/0
TC	**T/C -40C/125C	-40C/+125C (500,1000 Cycles)	-	3/231/0	3/231/0
TC	**T/C -55C/125C	-55C/+125C (500,1000 Cycles)	_	3/231/0	3/231/0

^{**} Preconditioning was performed for Temperature Cycle as applicable

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

⁻ The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles



5x6 QFN Q5D Power Block Qualification Summary

NCH MOSFET - Gen 2.0 30-10

C SD87353Q5D Qualification Test Summary							
Stress	Conditions	Test Duration	Sample Size	Results			
HTRB	150°C/80% Rated Vds	1K hrs	3 lots x 77 units	Pass			
HTGB	150°C/80% Rated Vgs	1K hrs	3 lots x 77 units	Pass			
THB	85°C/85%R.H./80% Rated Vds	1K hrs	3 lots x 77 units	Pass			
Autoclave	121C/100% RH	96 hrs	3 lots x 77 units	Pass			
Intermittent Op Life	Delta Tj = 100°C 2 min on/2 min off	10K cycles	3 lots x 77 units	Pass			
Temp Cycle	-40°C to 125°C	1K cycles	3 lots x 77 units	Pass			

Pass = 0/77 x 3 lots

MSL1 preconditioning performed on devices prior to THB, Autoclave, & Temp Cycle stresses

- External Visual @ 40X
- Temp Cycle: -40°C to +60°C, 5 cycles, 10 min dwell
- Bake: 24 hours @ 125°C
- Damp Heat: 168 hours @ 85°C/85% RH (Level 1)
- 3X reflow + flux + rinse, 260°C Pb free reflow temp

Original full qualification on CSD87353Q5D was run at PSi (above table). Clark assembly site is qualified by similarity since full qualification of 3 lots on CSD87350Q5D and full qualification of 1 lot on CSD87353Q5D was performed at Clark.

	C SD87353Q5D Qualification Test Summary							
Stress	Conditions	Test Duration	Sample Size	Results				
HTRB	150°C/80% Rated Vds	1K hrs	1 lot x 77 units	Pass				
HTGB	150°C/80% Rated Vgs	1K hrs	1 lot x 77 units	Pass				
THB 85°C/85%R.H./80% Rated Vds		1K hrs	1 lot x 77 units	Pass				
Autoclave	121C/100% RH	96 hrs	1 lot x 77 units	Pass				
Intermittent Op Life	Delta Tj = 100°C 2 min on/2 min off	10K cycles	1 lot x 77 units	Pass				
Temp Cycle -40°C to 125°C		1K cycles	1 lot x 77 units	Pass				

TI Information - Selective Disclosure

Texas Instruments, Incorporated

PCN#20170510000C

Qualification Report

CSD87334Q3D/CSD58899Q3D Qual for AP3

Approve Date 06-Jul-2017

Product Attributes

Attributes	Qual Device: CSD58899Q3D	Qual Device: CSD87334Q3D	QBS Product Reference: CSD87334Q3D	QBS Product Reference: CSD87334Q3D	QBS Product/Package Reference: CSD87334Q3D
Assembly Site	AMKOR AP3	AMKOR AP3	CLARK-AT	CLARK AT	AMKOR AP3
Package Family	QFN/SON	QFN/SON	QFN/SON	QFN/SON	QFN/SON
Flammability Rating	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0
Wafer Fab Supplier	CFAB CFAB	CFAB CFAB	CFAB CFAB	CFAB CFAB	CFAB CFAB
Wafer Process	FET_NCH_LV_GEN2.1 FET_NCH_LV_GEN2.1	FET_NCH_LV_GEN2.1 FET_NCH_LV_GEN2.1	FET_NCH_LV_GEN2.1 FET_NCH_LV_GEN2.1	FET_NCH_LV_GEN2.1 FET_NCH_LV_GEN2.1	FET_NCH_LV_GEN2.1 FET_NCH_LV_GEN2.1

- QBS: Qual By Similarity
- Qual Devices qualified at LEVEL1-260C: CSD87334Q3D, CSD58899Q3D
- Devices contain multiple dies: CSD58899Q3D, CSD87334Q3D

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: CSD58899Q3D	Qual Device: CSD87334Q3D	QBS Product Reference: CSD87334Q3D	QBS Product Reference: CSD87334Q3D	QBS Product Reference: CSD87334Q3D
AC	Autoclave 121C	96 Hours	-	-	3/231/0	-	-
ED	Electrical Characterization	Per Datasheet Parameters	-	-	3/90/0	-	-
CDM	ESD - CDM	2000 V	-	-	1/3/0	-	-
НВМ	ESD - HBM	4000 V	-	-	1/3/0	-	-
HTGB	High Temperature Gate Bias, 150C	1000 Hours	-	-	3/231/0	1/77/0	-
HTRB	High Temperature Reverse Bias, 150C	1000 Hours	-	-	3/231/0	1/77/0	-
IOL	Intermittent Operating Life	10000 Cycles	-	1/77/0	3/231/0	-	-
TC	Temperature Cycle, -55/125C	1000 Cycles	-	-	3/231/0	-	3/231/0
THB	Biased Temperature and Humidity, 85C/85%RH	1000 Hours	-	1/77/0	3/231/0	-	-
UHAST	Unbiased HAST, 130C/85%RH	96 Hours	-	1/77/0	-	-	-

⁻ Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at Tl's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

Qualification Report

CSD87331Q3D/CSD58889Q3D Qual for Clark-AT

Approve Date 06-Jul-2017

Product Attributes

Attributes	Qual Device: CSD58889Q3D	Qual Device: CSD87331Q3D	Qual Device: CSD87330Q3D
Assembly Site	CLARK	CLARK	CLARK
Package Family	QFN/SON	QFN/SON	QFN/SON
Flammability Rating	UL 94 V-0	UL 94 V-0	UL 94 V-0
Wafer Fab Supplier	CFAB CFAB	CFAB CFAB	CFAB CFAB
Wafer Process	FET_NCH_LV_GEN2.0 FET_NCH_LV_GEN2.0	FET_NCH_LV_GEN2.0 FET_NCH_LV_GEN2.0	FET_NCH_LV_GEN2.0 FET_NCH_LV_GEN2.0

- QBS: Qual By Similarity
- Qual Devices qualified at LEVEL1-260CX: CSD58889Q3D, CSD87331Q3D
- Devices contain multiple dies: CSD58889Q3D, CSD87331Q3D

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: CSD58889Q3D	Qual Device: CSD87331Q3D	QBS Product:
AC	Autoclave 121C	96 Hours	-	-	3/231/0
ED	Electrical Characterization	Per Datasheet Parameters	-	٠	-
CDM	ESD – CDM	2000 V	-	-	-
HBM	ESD – HBM	4000 V	-	-	-
HTGB	High Temperature Gate Bias, 150C	1000 Hours	-	•	3/231/0
HTRB	High Temperature Reverse Bias, 150C	1000 Hours	-	•	3/231/0
IOL	Intermittent Operating Life	10000 Cycles	-	1/77/0	3/231/0
TC	Temperature Cycle, - 55/125C	700 Cycles	-	1/77/0	3/231/0
TC	Temperature Cycle, - 55/125C	1000 Cycles		1/77/0	3/231/0

THB	Biased Temperature and Humidity, 85C/85%RH	1000 Cycles	-	1/77/0	3/231/0
UHAST	Unbiased HAST, 110C/85%RH	264 Hours	-	1/77/0	-

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

Group 4 Qualification Report

TPS65131RGE: add Clark AT as second assembly/FT site
Approve Date 19-July-2017

Product Attributes

Attributes	Qual Device: TPS65131RGER	QBS Product Reference: TPS65130RGE	QBS Product Reference: TPS65130RGER	QBS Package Reference: ONET4291VARGPR
Assembly Site	CLARK AT	CAR	CLARK AT	CLARK-AT
Package Family	VQFN	VQFN	VQFN	QFN
Flammability Rating	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0
Wafer Fab Supplier	DM0S5	DFAB	DFAB	JAZZ
Wafer Process	LBC4X	LBC4	LBC4X	RFSIGE

- QBS: Qual By Similarity
- Qual Device TPS65131RGER is qualified at LEVEL2-260CG

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: TPS65131RGER	QBS Product Reference: TPS65130RGE	QBS Product Reference: TPS65130RGER	QBS Package Reference: ONET4291VARGPR
ED	Electrical	Per Datasheet	_	1/5/0	_	_
	Characterization	Parameters	_	1/3/0	_	-
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	-	1/77/0
HBM	ESD - HBM	3000V	-	1/3/0	-	-
CDM	ESD - CDM	1000V	-	1/3/0	-	-
HTOL	Life Test, 140C	480 Hours	-	-	-	1/77/0
HTOL	Life Test, 150C 7.0V	300 Hours	-	1/77/0	-	-
LU	Latch-up	(per JESD78)	-	1/5/0	-	-
MQ	Manufacturability	(per mfg. Site	Pass	Pass	Pass	Pass

	(Assembly)	specification)				
MQ	Test MQ	(per mfg. Site specification)	Pass	-	-	Pass
MSL	Thermal Path Integrity	Level 2-260C	-	-	Pass	-
PD	Physical Dimensions		-	-	-	1/5/0
TC	Temperature Cycle, -65/150C	500 Cycles	-	-	-	1/77/0
TS	Thermal Shock, - 65/150C	1000 Cycles	-	1/77/0	-	-
WBP	Bond Pull	Wires	-	-	-	1/76/0
WBS	Bond Shear	Wires	-	-	-	1/76/0

⁻ Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at Tl's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

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